

INFORMATION DISCLOSURE STATEMENT BY APPLICANT <small>(Not for submission under 37 CFR 1.99)</small>	Application Number		10553030	
	Filing Date		2006-06-15	
	First Named Inventor		Armin Gerhard Aberle	
	Art Unit		1762	
	Examiner Name			
	Attorney Docket Number		SFC 302	

U.S. PATENTS						
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	1	3951633	A	1976-04-20	Danihel	

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	1	00/28602	WO	A1	2000-05-18	Pacific Solar Pty Limited	

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1	Widenborg, P., and Aberle, A., "Thick Poly-Si Films Fabricated By the Aluminum-Induced Crystallization Bi-Layer Process on Glass Substrates," Conference Record of the 29th IEEE Photovoltaic Specialists Conference 20020519 - 20020524 New York, N.Y.; IEEE, US, vol. CONF. 29, 19 May 2002 (2002-05-19), pages 1206-1209, XP010666498 ISBN: 978-0-7803-7471-3	<input type="checkbox"/>
2	Widenborg, P., and Aberle, A., "Surface Morphology of Poly-Si Films Made By Aluminum-Induced Crystallisation on Glass Substrates," Journal of Crystal Growth, Vol. 242, no. 3-4: p. 270-282 (July 1, 2002).	<input type="checkbox"/>
3	Widenborg, P. et al., "Back Electrode Formation for Poly-Si Thin Film Solar Cells on Glass Having AlC-grown Seeding Layer," Solar Energy Materials and Solar Cells, vol. 74, no. 1-4: p. 305-314 (October 1, 2002).	<input type="checkbox"/>
4	Copy of Examination Report pursuant to Article 94(3) EPC from related European Patent Application No. 04 721 778.1 - 2111, dated December 23, 2008.	<input type="checkbox"/>

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